# EMTG30

## 30KB Ultra Low Cost Flash Smart Card IC

#### **Environment**

- ullet Voltage Supply Class A, B: 3.0V to 5.0V  $\pm$  10%
- □ -25 to +85 °C Operating Temperature
- Max supply current 6mA @ 15MHz, Class B
- □ > 4 kV ESD Protection HBM

#### **CPU**

- □ Software compatible CMOS 80X51 industry standard
- ☐ Accelerated architecture with 16 bit CPU performance level
- Up to 30 MHz internal CPU clock

#### **Idle Modes**

- □ Idle and Stop mode selectable modes
- □ NVM update operation with CPU in idle/halt mode
- □ IO Transmission and Reception with CPU in idle mode
- Max Idle current / Clock stopped : 100 uA

## Security

- □ Unique chip identification number
- Notification of tampering
- Internal clock generation
- □ IC operates under regulated voltage
- □ DPA/SPA resistance mechanisms
- Under / Over voltage sensors (Vcc)

## **Memory Control**

- ☐ General Purpose Non Volatile Memory: GPNVM
- □ Secure Memory Management Mechanism
- ☐ Fast Byte program: 40 us / Byte
- GP NVM Page Erase: 2 ms

#### 1/0

- □ ISO 7816-3 compliant electrical interface
- □ ISO 7816-3 compliant interface with T=0 and T=1 protocols
- ETU Timer/Counter replacing 8051 T0/T1 Timers

#### **Memories**

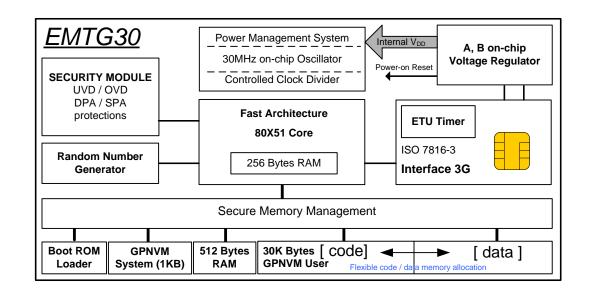
- 768 bytes RAM (256B Local RAM + 512B XRAM)
- → 30KB GPNVM (User) = 240 Pages of 128 B.
  - User Code, constant storage (ROM)
  - User Non Volatile Data storage (EEPROM)
- ☐ 1KB GPNVM (System) = 8 Pages of 128 B
  - System parameters
  - Loader extensions
  - Backup buffer / hard API code
- □ 10 years data retention
- ☐ GPNVM Cycling Endurance > 100 K cycles
- BootROM loader T0 and T14 compatible
- Boot loader commands set extension capabilities

#### **Chip Forms**

- 8" Wafer sawn or unsawn
- Back grinding and distressing options
- ☐ 180 microns max thickness
- Modules

## **Typical Application:**

- ☐ SIM card GSM Phase2 or Phase2+ 16KB
  - Development tools fully integrated within Keil uVision2/3
- ✓ DevKit emulator, examples, documentation samples



## EMTG30

#### Introduction

EMTG30 is a member of the Theseus family of devices designed specifically for smart card applications. It is software compatible with the industry standard 8051 micro-controller, to guarantee the maximum availability of qualified software. The hardware implementation of the core is a modern design not relying on microcode, with an increase of up to 4 times on a standard 8051's clocks per instruction.

Security of the family of devices makes them particularly suitable in electronic commerce and sensitive data areas. This is accomplished in hardware, with not only protection against out of parameter operation of the device, but hardware memory management to protect against software security attacks. The CPU clock is derived from its own internal oscillator, so preventing attacks by clock manipulation, or extrapolating program execution by monitoring current variations on clock edges.

#### **General Purpose Non Volatile Memory (GPNVM)**

The General Purpose Non Volatile Memory offers ultra low cost implementation of traditional EEPROM based smart card ICs using one unique memory instance for code and data storage. This one memory solution provides compact implementation offering at the same time a maximum flexibility. Therefore all code size footprint reduction will directly benefits to the application.

A simple and secure memory protection mechanism is relying on a flexible border between code and data space.

With up to a 30KB GPNVM on chip memories EMTG30 eradicates the need for memory bank switching either for data and code space.

The organisation of GPNVM in 128 bytes per pages combined with efficient page management methods are increasing application level performances such as:

- High performances memory update
- High resistance to page tearing
- Extension of application level effective page cycling endurance
- Simple implementation of anti-tearing mechanism

An additional GPNVM system area of 1KB is available. This system area hosts device systems parameters. The remaining area could be used for several purposes such boot loader commands extension, GPNVM update backup buffer, hardware API functions etc...

This means that reel User's available memory is actually larger than 30KB.

#### Serial interface

EMTG30 offers a unique serial interface compliant with the ISO 7816-3 specification with several modes implemented allowing serial connections at 9600 up to 357K bits per second at 3.57MHz. EMTG30 supports T=0 asynchronous half duplex character transmission protocol, T=1 asynchronous half duplex block transmission and a proprietary T=14 protocol used for fast loading of Code into the OTP by the card manufacturer. It handles minimum guard time requirements between characters specified by ISO7816-3 specification automatically. EMTG30 is designed to be compatible with the ISO7816-3 specification defining the characteristics of Integrated Circuit Cards commonly referred to as smart cards.

#### **Random Number Generator**

The on chip random number generator is fully Fips140-2 compliant, providing a rapid stream of truly random numbers. This allows use of the random numbers generated beyond just the provision of numbers for randomising transmissions or generating keys.

#### Clocks

EMTG30 has its own internal oscillator this allows the core of the device to be independent of the external clock. The processor can also be clocked much faster than the IO CLK signal. This ensures the elimination of fraudulent attacks involving frequency jitter and unequal mark space ratios. The internal clock generator is connected to the core via a divider that is under the control of the software. This allows the Operating System writer to control the trade off between execution speed and power drawn by the device. Extending battery life in hand help applications where slow interfaces are involved.

## Anti tampering

The EMTG30 has extensive anti tampering provision including the monitoring of the connection to the device to ensure that deviations beyond a prescribed criteria result in the device being closed down before its operating conditions are violated.

## On chip voltage regulators

Several on chip regulators isolate the various elements of the device from variations and fluctuations in the supply voltage. This allows elements to be characterised precisely, as they operate at one fixed voltage, which in turn maximises the endurance of the device.

## Technology

This product is using superior Flash memory SuperFlash Technology licensed from SST and SuperFlash is a registered trademark of SST (Silicon Storage Technology Inc.).

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# EMTG30

#### **Technical Data**

**Absolute Maximum Ratings** 

Parameter	Symbol			Unit	
		min	typical	max	
Supply Operating Volt	V <sub>cc</sub>	-0.3		6	V
Voltage at remaining pin	$V_{pin}$	V <sub>ss</sub> -0.3		V <sub>cc</sub> +0.3	V
Power dissipation	P <sub>tot</sub>			+60	mW
Storage temperature	I <sub>ccl</sub>	-40		+125	°C

## **DC Characteristics**

Parameter	Symbol	Limit Values				
		min	typical	max		
Operating temperature	T <sub>A</sub>	-25		+85	°C	
Supply Voltage Class A,B	V <sub>cc</sub>	2.7	3/5	5.5	V	
Supply Current Class B	I <sub>cc</sub>			6 (Note 1)	mA	
Supply Current idle	I <sub>ccl</sub>			200 (Note 2)	μА	
Supply Current stopped	I <sub>ccS</sub>			100 (Note 3)	μА	

Note 1: The supply current refers to clock frequency of 5 Mhz

Note 2: The supply current at 3.3V and a clock frequency of 1 Mhz, at +25  $^{\circ}$ C

Note 3: The supply current at 3.3V and +25 °C

### IO pin:

Parameter	Symbol	Conditions	min	max	Unit
H input voltage	V <sub>IH</sub>	I <sub>Ihmax</sub> =±20μA	0.7 * V <sub>cc</sub>	V <sub>cc</sub>	V
L input voltage	V <sub>IL</sub>	$I_{IL max} = \pm 20 \mu A$	-0.3	0.8	V
H output voltage (Note 1)	V <sub>OH</sub>	I <sub>Ohmax =</sub> +20μA	0.7 * V <sub>cc</sub>	V <sub>cc</sub>	V
L output voltage	V <sub>OL</sub>	I <sub>Olmax</sub> = -1mA	0	0.4	V
Rise Fall Time	t <sub>r</sub> , t <sub>F</sub>	$C_{IN} = C_{OUT} = 30 \text{ pF}$		1	μS

NOTE 1: Assumes  $20K\Omega$  Pull up resistor on interface device

## Clock (CLK)

Parameter	Symbol	Condition	Min	Max	Unit
H output voltage	V <sub>OH</sub>	$I_{Ohmax} = +20 \mu A$	V <sub>cc</sub> -0.7	V <sub>cc</sub>	V
L output voltage	V <sub>OL</sub>	$I_{Olmax} = -20 \mu A$	0	0.5	V
Rise Fall Time	t <sub>r</sub> , t <sub>F</sub>	$C_{IN} = C_{OUT} = 30 \text{ pF}$		9% CLK	
				period	

## Reset(RST)

Parameter	Symbol	Condition	Min	Max	Unit
H output voltage	V <sub>OH</sub>	$I_{Ohmax} = +20 \mu A$	V <sub>cc</sub> -0.7	V <sub>cc</sub>	V
L output voltage	V <sub>OL</sub>	$I_{Olmax} = -20 \mu A$	0	0.6	V
Rise Fall Time	t <sub>r</sub> , t <sub>F</sub>	$C_{IN} = C_{OUT} = 30 \text{ pF}$		400	μS

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